

Measurements with a Si-strip telescope

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Outline

- Telescope layout:
 - Setup
 - DAQ
 - DAQ to analysis interface
- Setup optimization:
 - Alignment
 - Calibration
 - Rotation of one sensor
 - Longitudinal shift of one sensor
 - Positioning and resolution
- Scattering measurements:
 - Setups
 - Measurements results
 - Comparison with simulations

Telescope setup



The telescope in its operational setup at COSY (Jülich)

Four boxes:

- 2 double sided Si-strip sensors
- 4 single sided Si-strip sensors

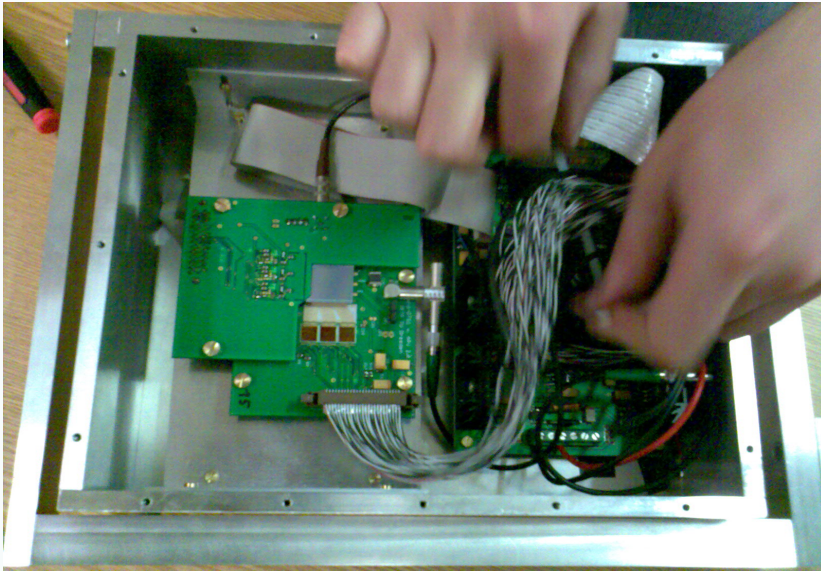
Sensors:

- 1.92cm x 1.92cm active area
- 300 μm thick
- 50 μm pitch
- 90° stereo angle (for double sided ones)

Trigger:

- 4 scintillators (2 before and 2 downstream from the telescope) - 3/4 coinc.

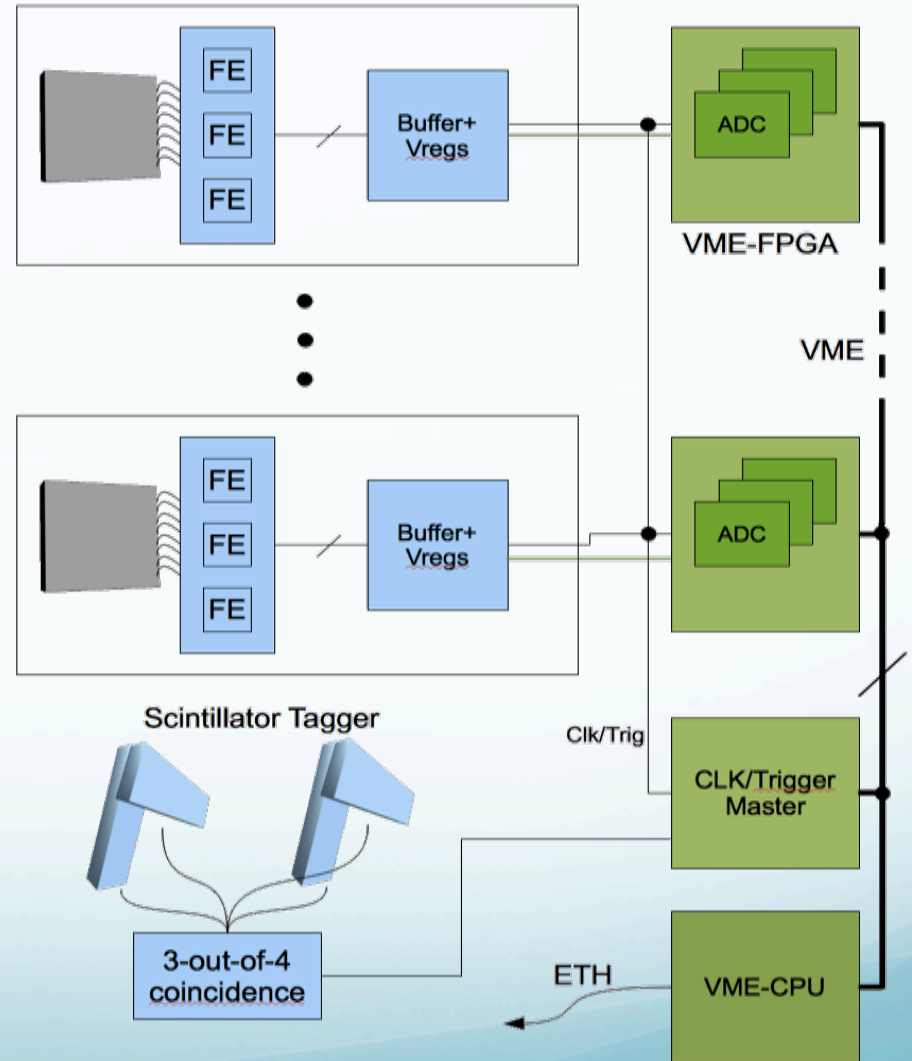
Telescope - DAQ



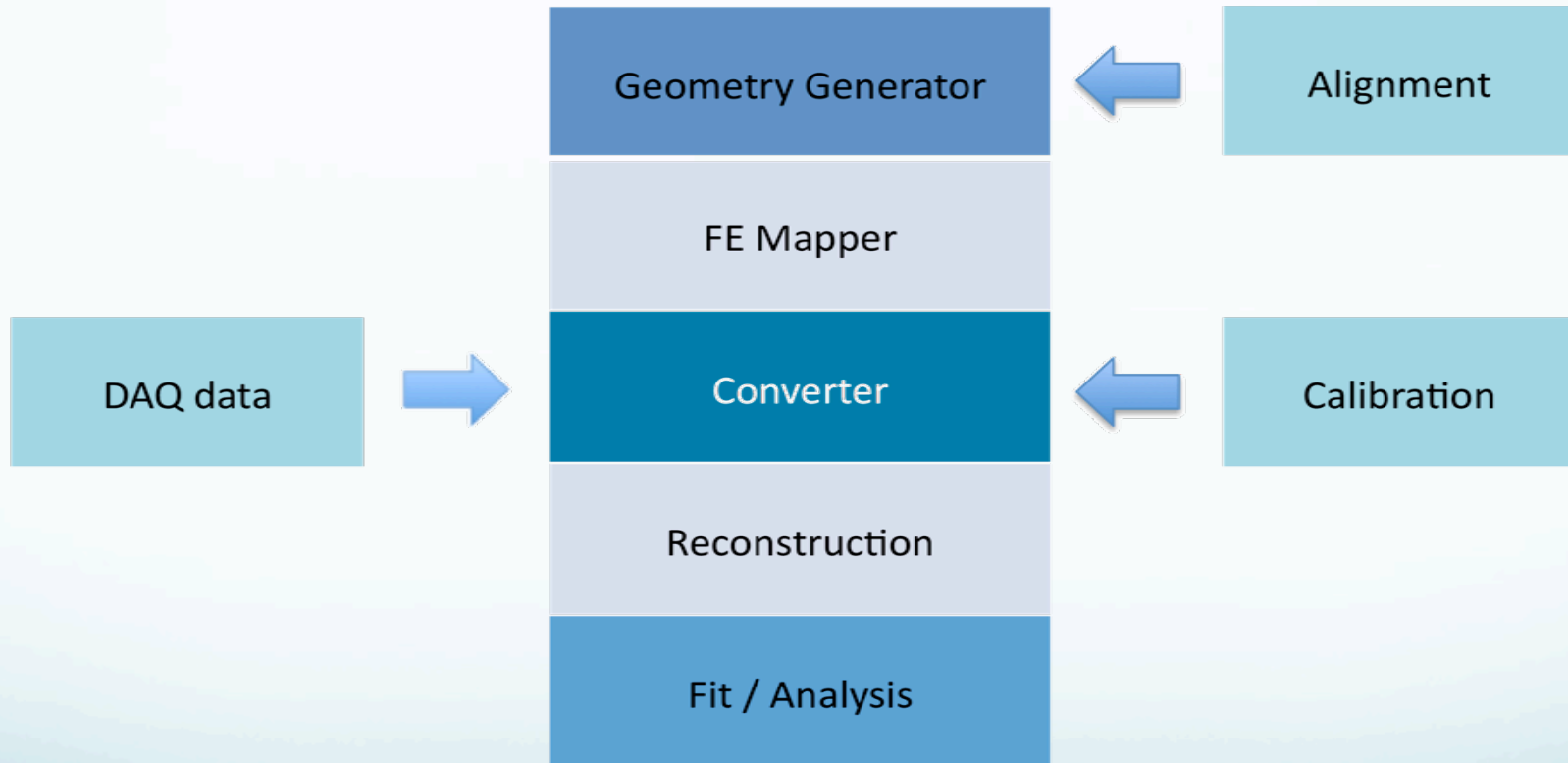
FEE: APV25-S1

Depletion voltage: ~ 60 V
p in n⁻ bulk
(n in n on the other side)

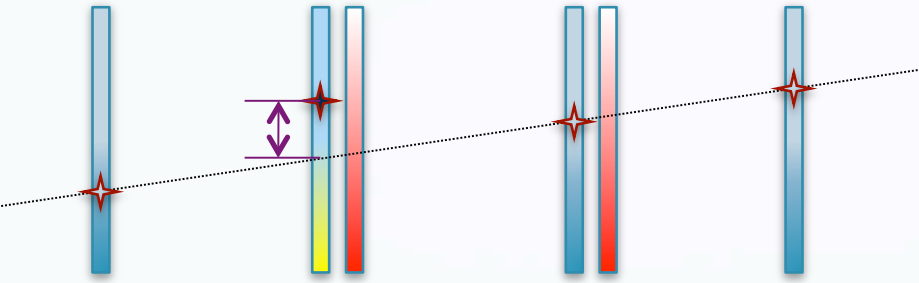
Readout AC coupled
Punch through bias
Max DAQ rates ~ 1 - 2 k evts/s



Telescope: from DAQ to analysis



Alignment



Iterative procedure to align sensors:

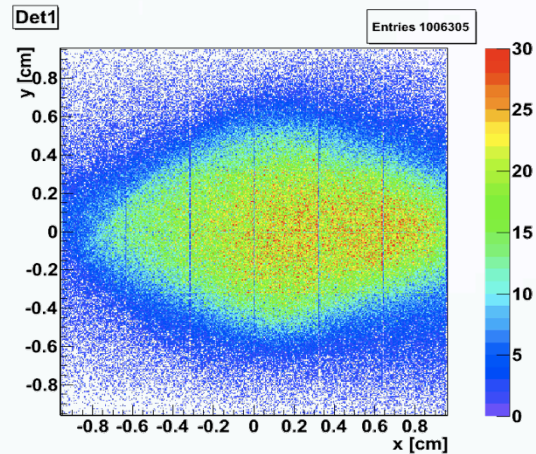
1. Measure residual on the 1st sensor
2. Correct the position of the 1st sensor
3. 2nd sensor... 6th sensor
4. Reiterate the whole loop

Energy Calibration

Realized in two steps:

- ✓ Same charge injected on each of the FE channels
→ to resolve differences in the response
- ✓ MIP hypothesis
→ to set an absolute ADC counts-to-energy-loss scale

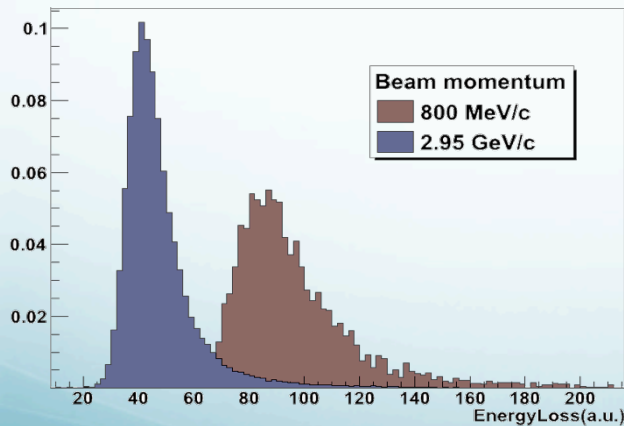
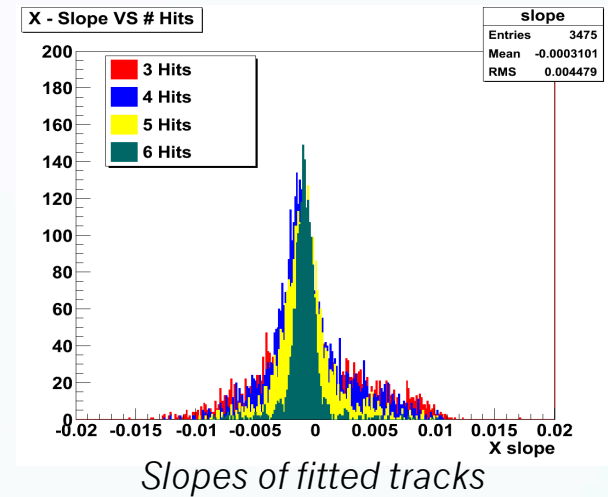
First measurements



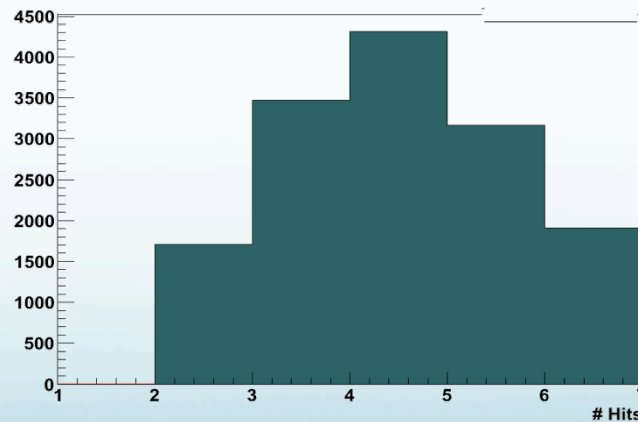
Beam profile: scint. overlap

First measurements:

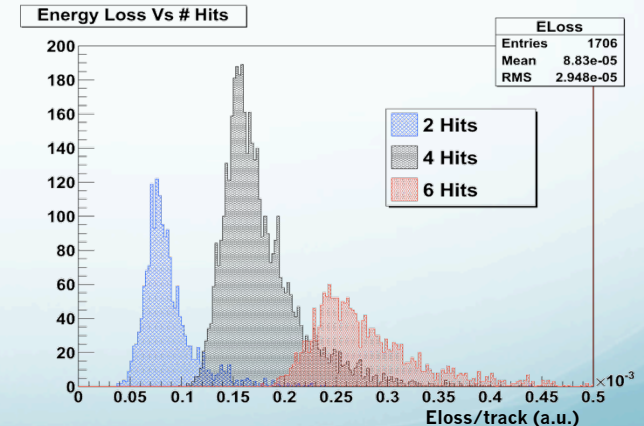
- ✓ behavior of the sensors
- ✓ experimental conditions
- ✓ benchmark of the tools



Eloss in a sensor with different beams

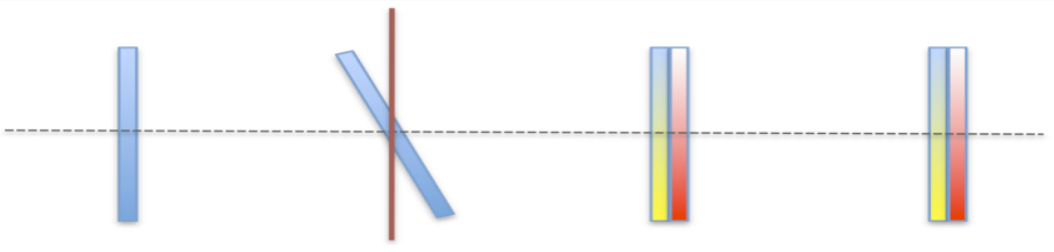


Hits / event



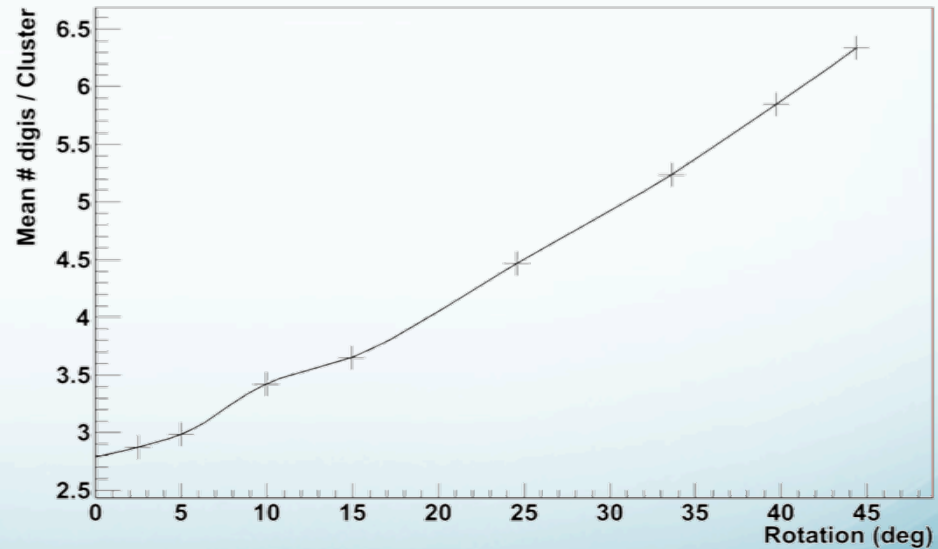
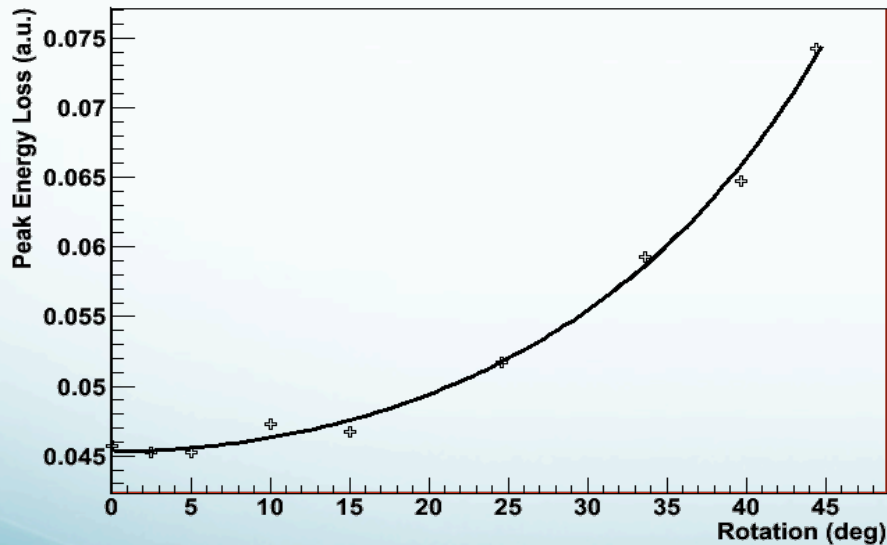
Eloss for tracks with different # of hits

Rotation of a sensor



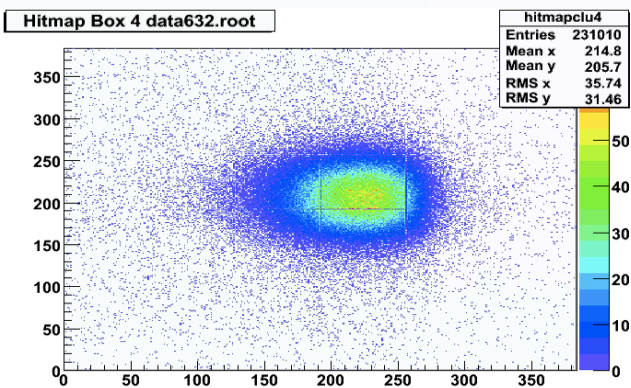
The second box was rotated:
Different beam incident angles

Effect of the rotation on energy loss and cluster size

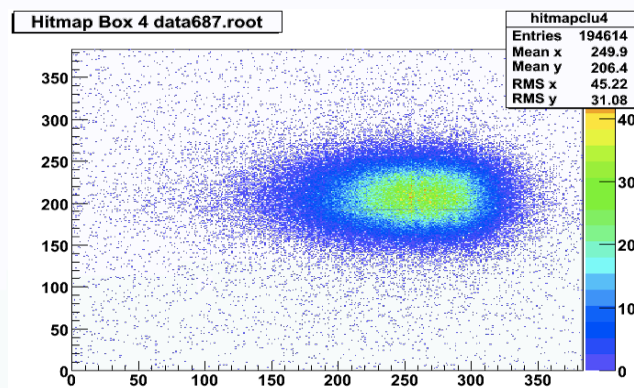


Measurements performed with 4 GeV electrons at DESY

Rotation - II

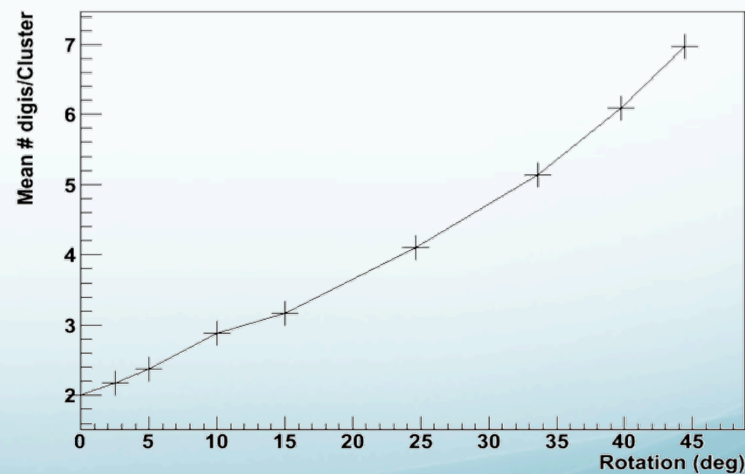
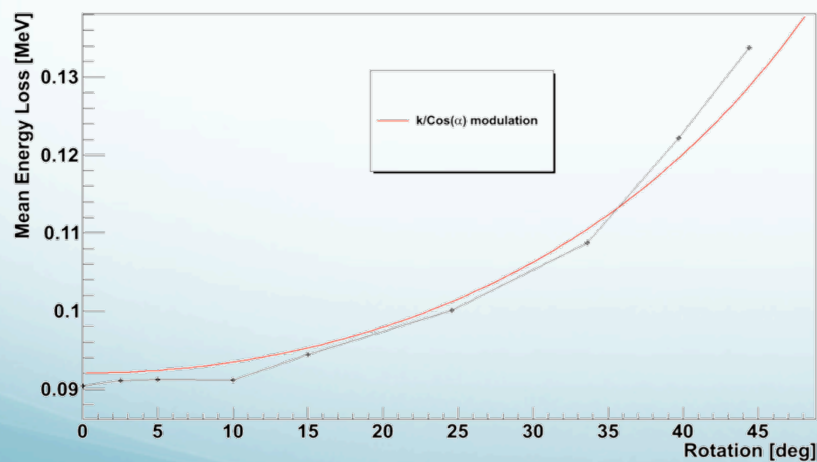


Normal position



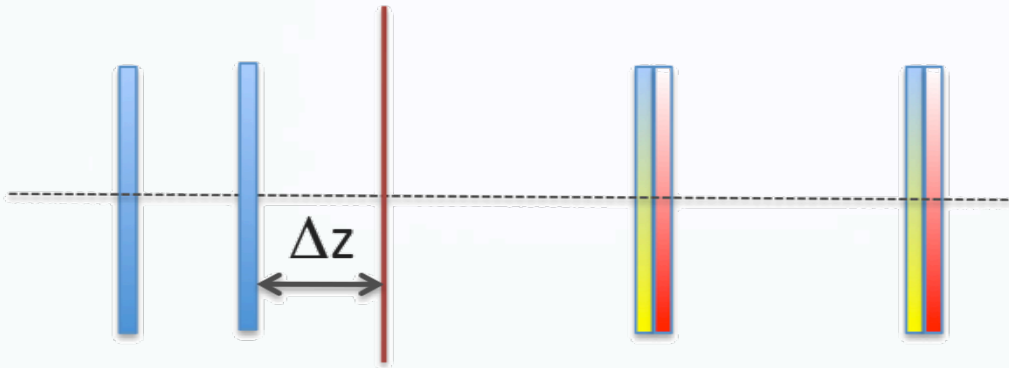
Box rotated of 40°

Hit distribution on the rotated box
2.95 GeV/c protons



Simulations of the previous setups, 4 GeV electrons

Translation of one sensor



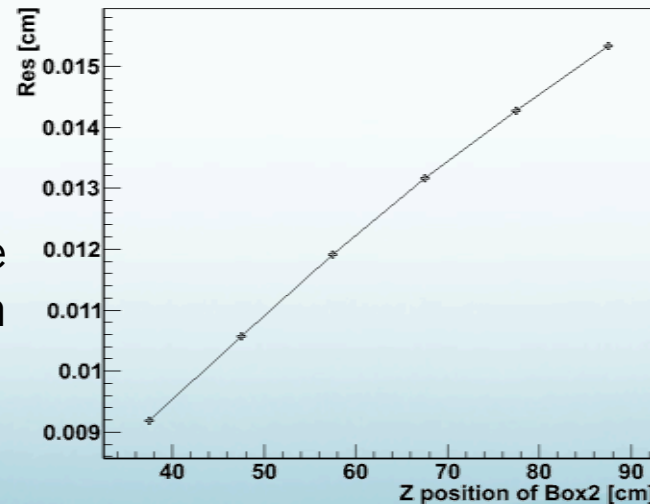
Longitudinal scan:

One sensor moved along the beam direction

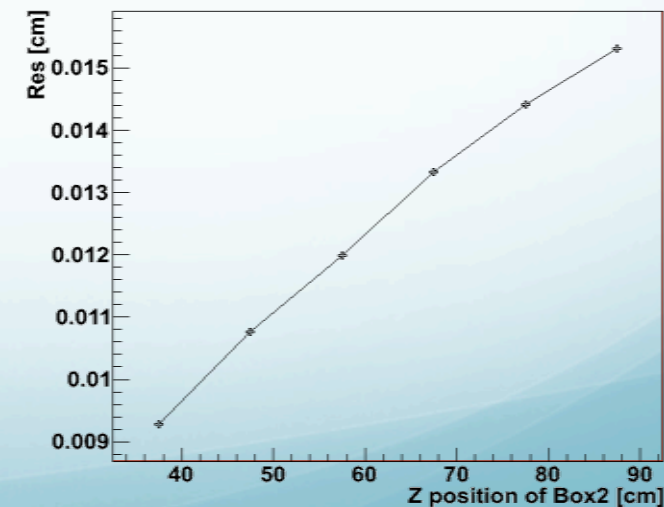
$$\text{RES} = \sqrt[4]{\sigma_1 * \sigma_2 * \sigma_3 * \sigma_4}$$

where σ_i is the width of the residuals distribution obtained on sensors i

X Resolution

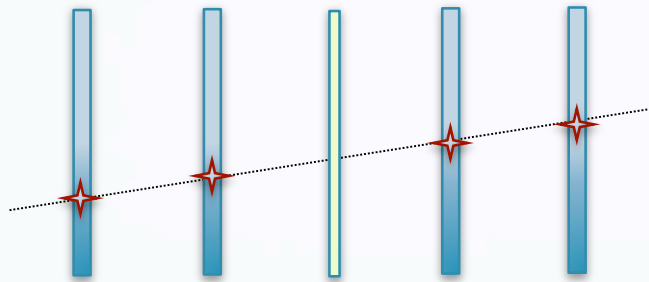


Y Resolution



Measurements with 3 GeV electrons at DESY

Positioning optimization



Simulations with 5 GeV e^-
and a 300 μm Si device

Setup	σ_x	σ_y
	μm	μm
A	56	53
B	16	16
C	34	34

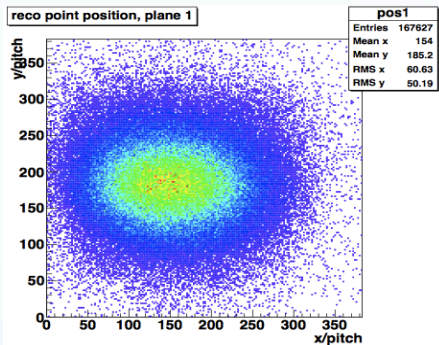
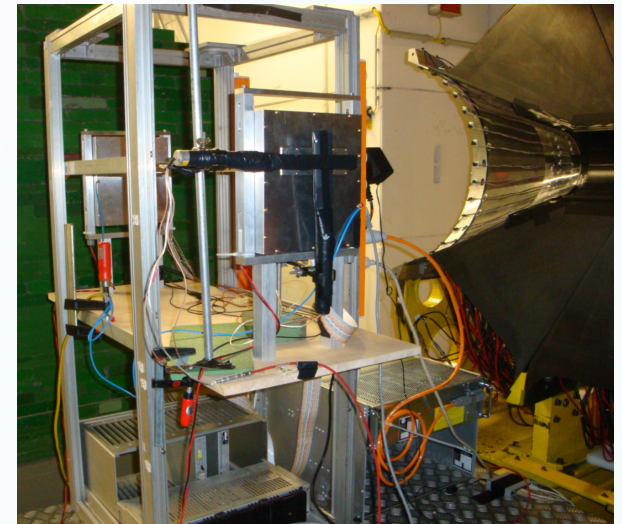
	B1	B2	Device	B3	B4
	z(cm)	z(cm)	z(cm)	z(cm)	z(cm)
A	16.	86.	110.	145.	185.5
B	90.	100.	110.	120.	130.
C	65.	85.	110.	139.	159.

Photon tests

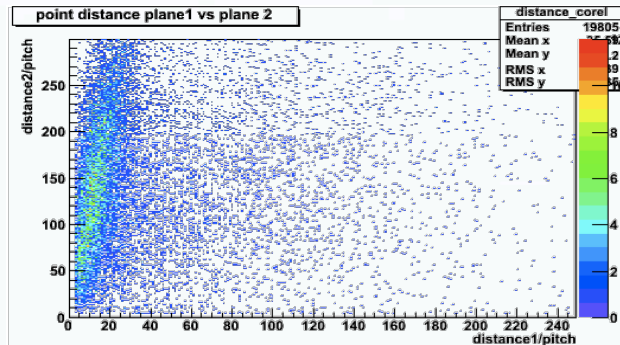
Electron ring → Bremsstrahlung photons (up to 3 GeV) → PP in a converter

2 Boxes equipped with double sided sensors

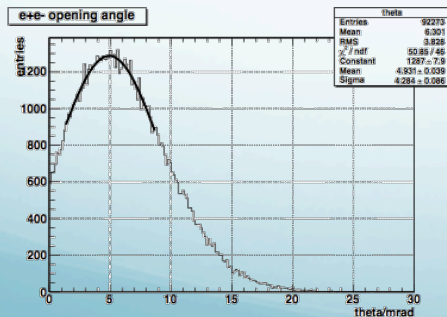
Scintillator as a converter



Hits on the 1st sensor
(2 hits/sensor events)



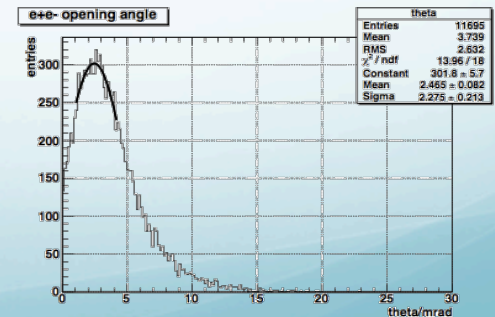
Correlation of the distance between two
hits on the two sensors



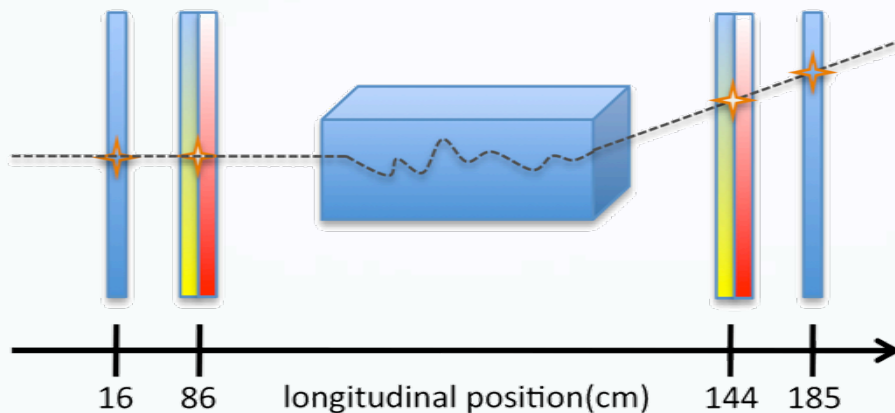
Distribution of the opening
angle of the e^+e^- pair

← Low E (~400 MeV)

Higher energies →



Scattering measurements

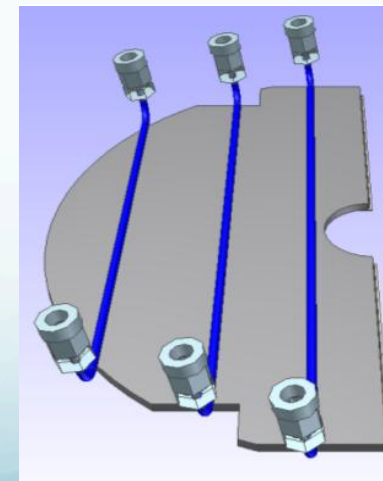


Beams:

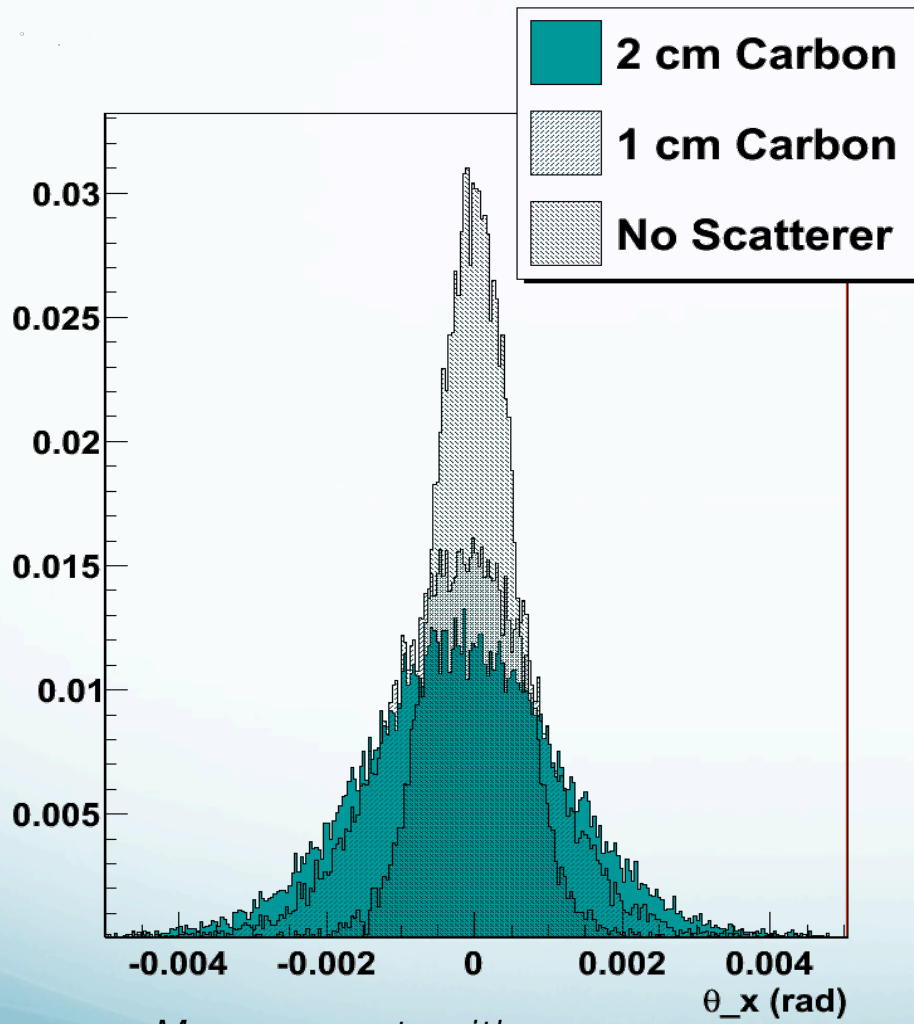
COSY Protons of 2.95 GeV/c
DESY Electrons of 1.5 GeV

Scatterers:

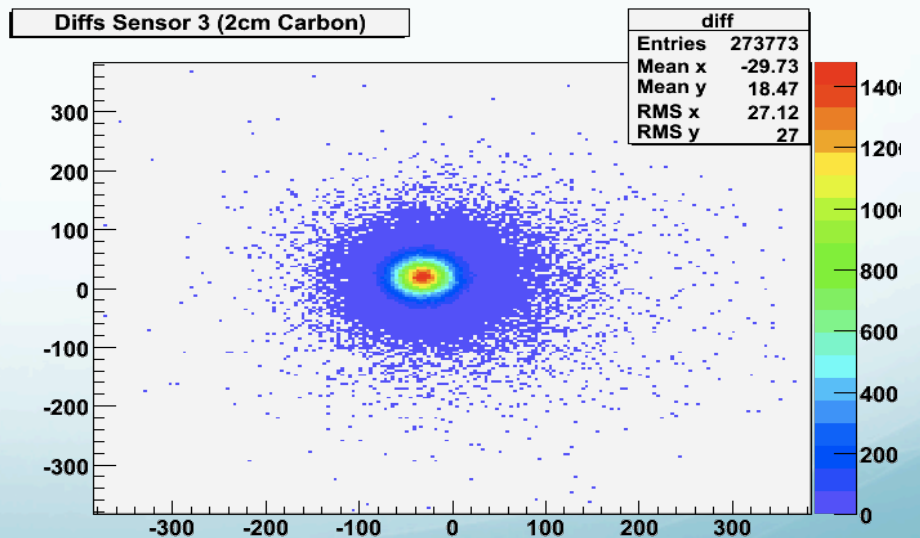
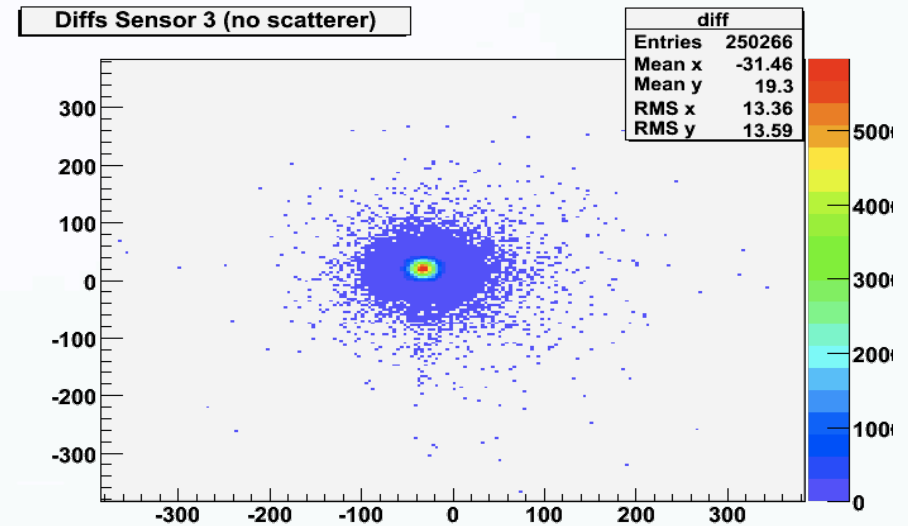
- 1 cm of C ($\rho \sim 1.79 \text{ g/cm}^3$)
- 2 cm of C ($\rho \sim 1.69 \text{ g/cm}^3$)
- 2.5 cm of carbon foam ($\rho \sim 0.52 \text{ g/cm}^3$)
- Carbon foils
- a prototype for support structures
(4mm C-foam with embedded cooling pipes)
($\rho \sim 1.1 \text{ g/cm}^3$)



Scattering measurements - II



Measurements with
2.95 GeV/c protons at COSY

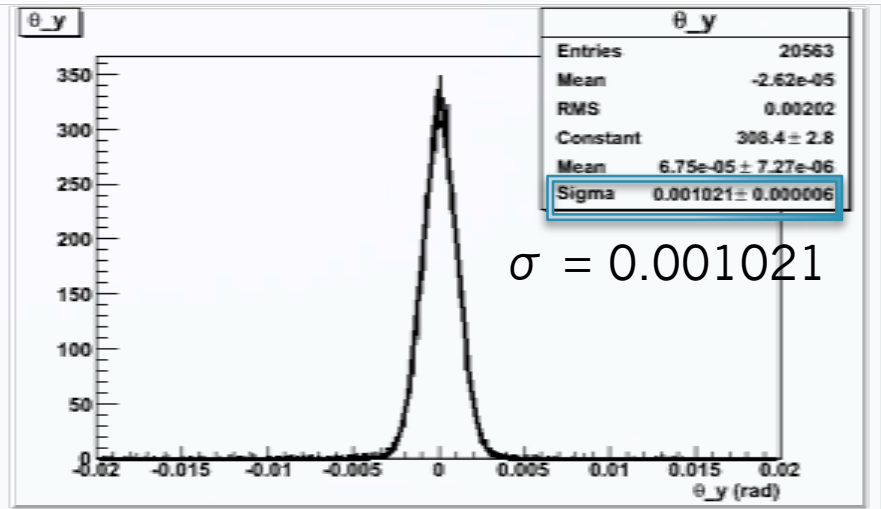
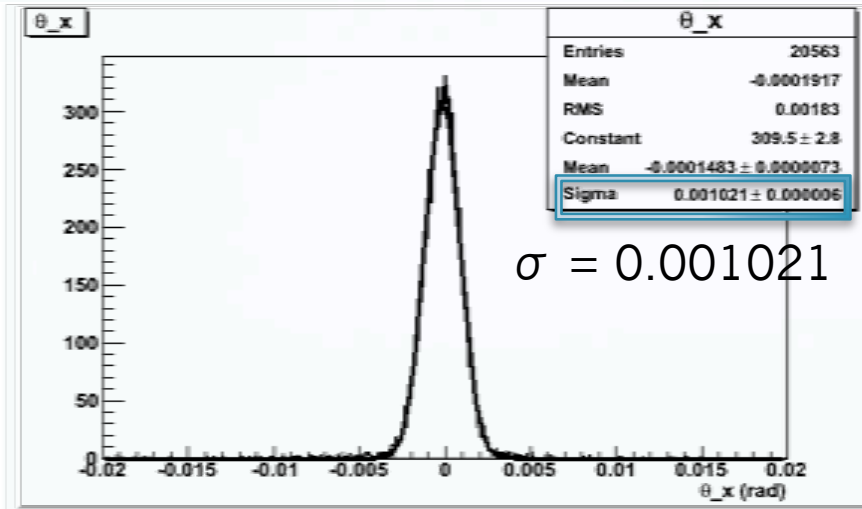


Simulations

- The setup used for simulations was the same as the one of the measurements
- Geo definition:
 - 6 silicon parallelepipeds with sizes $1.92\text{cm} \times 1.92\text{cm} \times 300\mu\text{m}$
- Beam definition: “single-particle” events, particles propagated from a few cm upstream the telescope
- No beam divergence (small effect due to geometry restrictions)
- Beam shot toward the center of the first box, parallel to the longitudinal axis
- Propagation realized with Geant3 (tested several scattering models without experiencing severe differences)

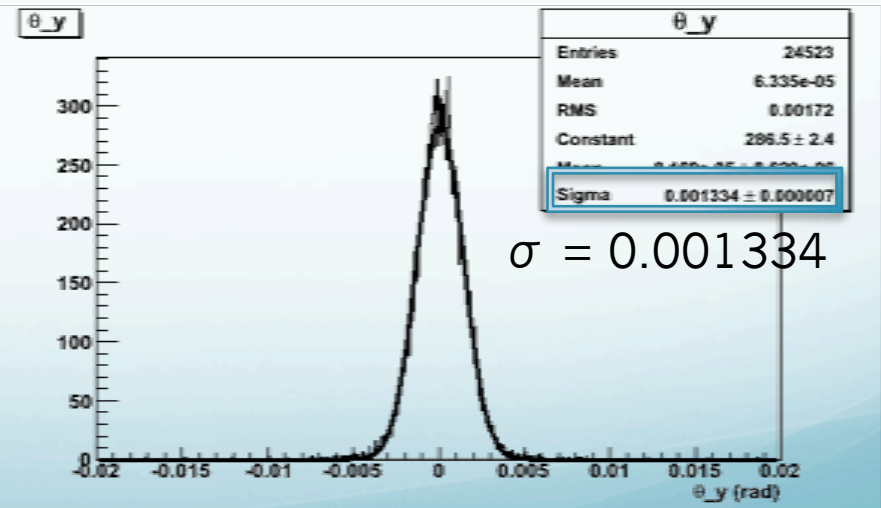
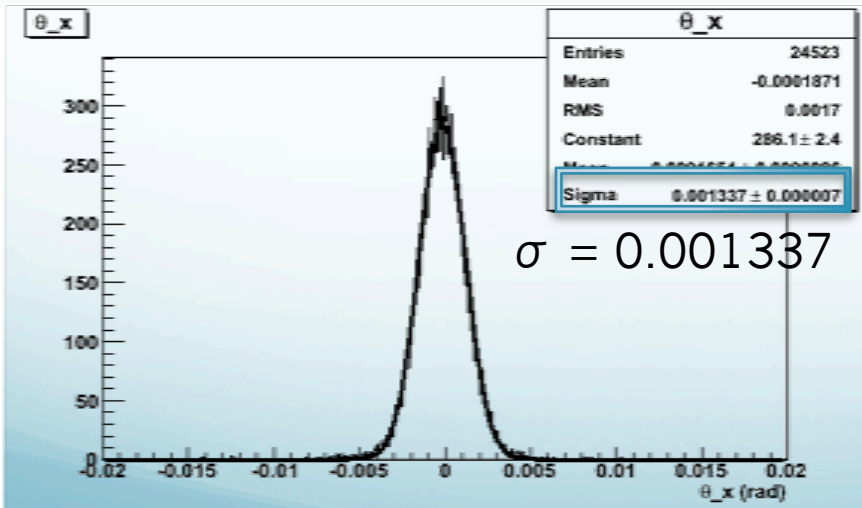
Results with protons

GEANT3 → Sigma 0.001011



2.95 GeV/c protons scattering in:

GEANT3 → Sigma 0.001334



1 cm of C-based material 2 cm of C-based material

Results with electrons

Scatterer	e ⁻ Mom.	Sigma Meas. (mrad)	Sigma Sim (mrad)
air	1 GeV/c	1.24	1.40
air	3 GeV/c	0.423	0.476
air	5.4 GeV/c	0.243	0.284
2.5 cm C-Foam	1 GeV/c	2.18	2.54
2.5 cm C-Foam	3 GeV/c	0.746	0.887
2.5 cm C-Foam	4 GeV/c	0.588	0.645
1 Cm C	1 GeV/c	2.48	2.89
1 Cm C	5.4 GeV/c	0.511	0.599
2 Cm C	1 GeV/c	3.15	3.82
2 Cm C	5 GeV/c	0.698	0.807
Foam Disk	1 GeV/c	1.76	1.87
Foam Disk	3 GeV/c	0.600	0.611
Foam Disk	4 GeV/c	0.471	0.483

Conclusions

- The telescope was successfully operating in several beam conditions
- Different setups have been tested
- The effects of rotations and positioning of the sensors has been studied
- Scattering measurements were performed
- A direct comparison between analysis and simulations allowed to validate our framework

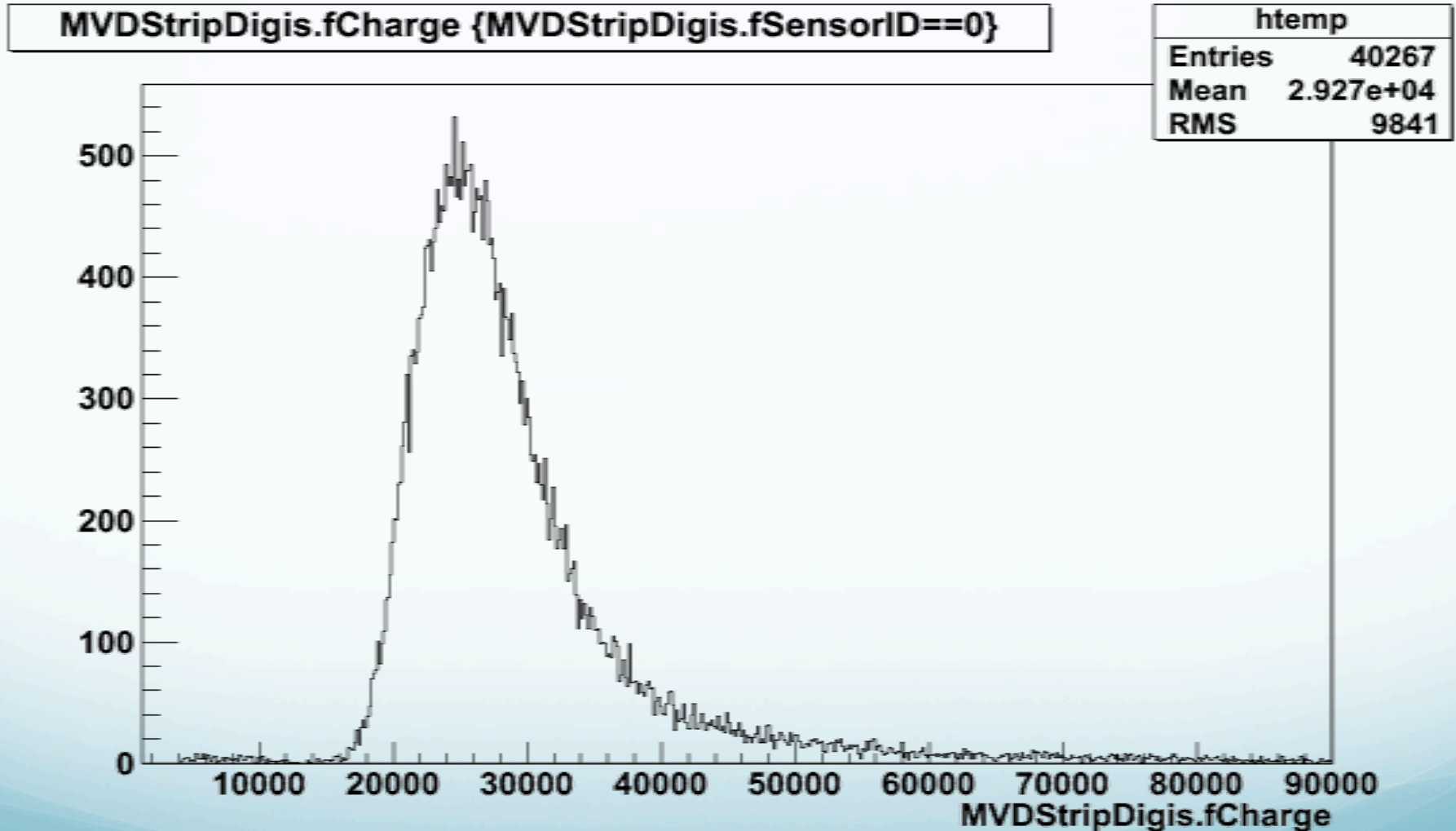


Thanks for your attention!



Backup slides

Rotation of One Sensor - Simulations

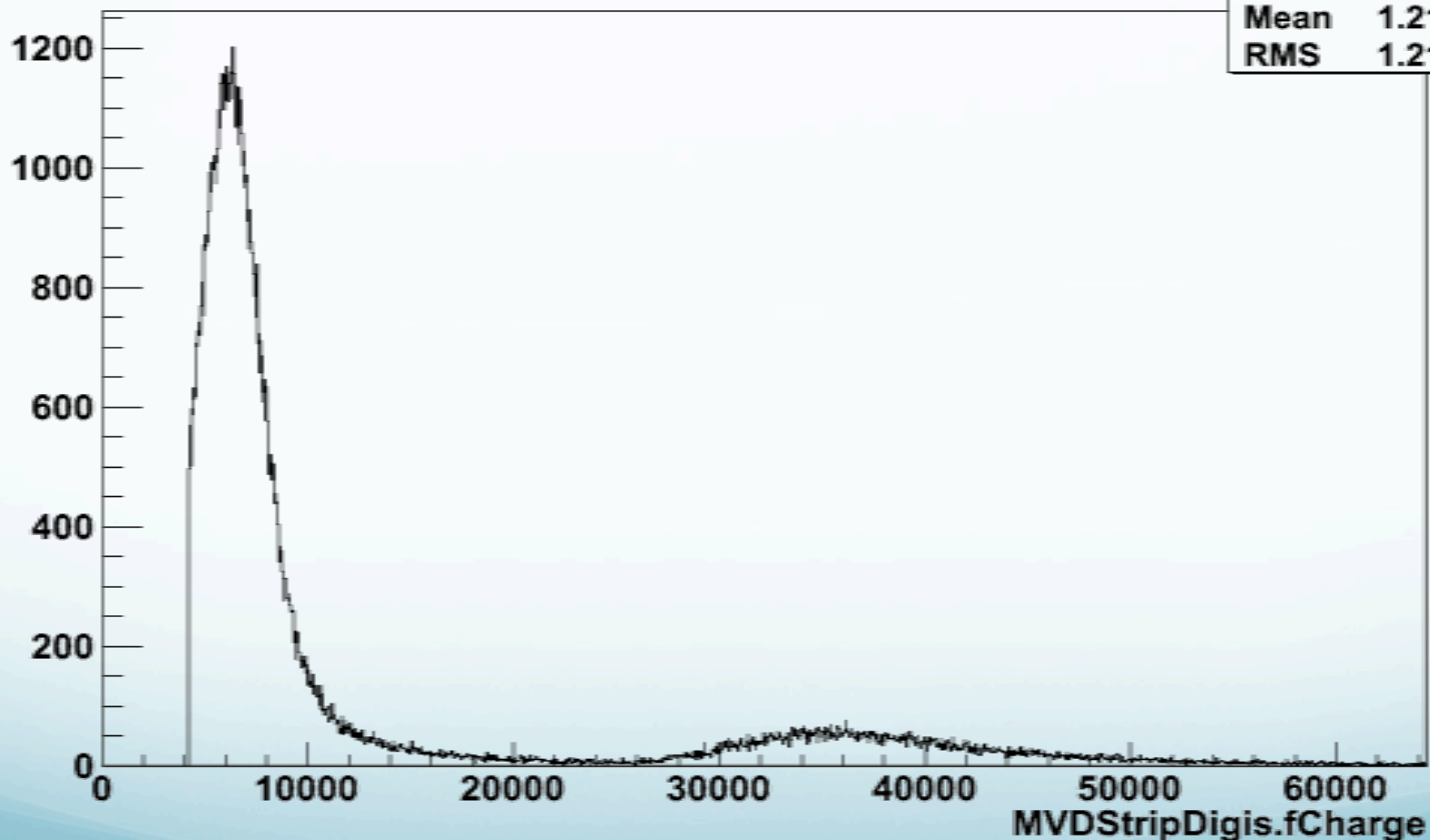


Electrons of 4 GeV - 0 deg rotation

Rotation of One Sensor - Simulations

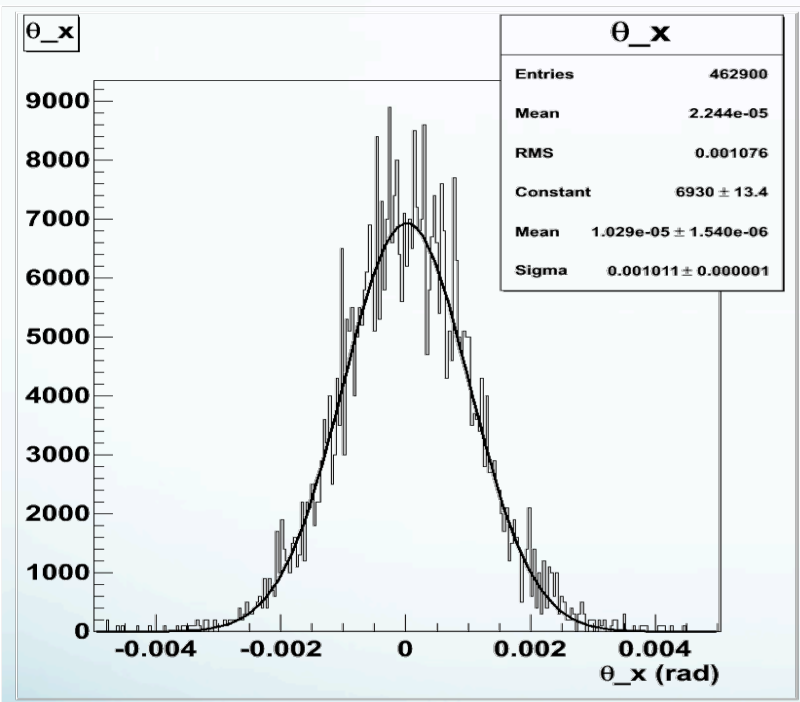
MVDStripDigis.fCharge {MVDStripDigis.fSensorID==1}

htemp	
Entries	129693
Mean	1.219e+04
RMS	1.214e+04



Electrons of 4 GeV - 44.4 deg rotation

Scattering distributions



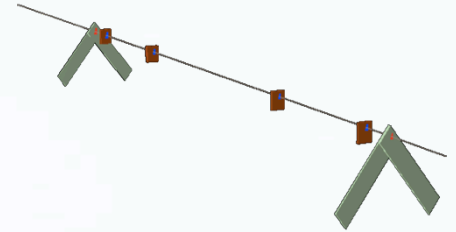
2.95 GeV/c protons scattering in 1 cm of C (density 1.79 g/cm³)

FEE to SIM maps

RW	SW	Detector Name
0	0	/TS_1/TTVol_0/TTDouble_0/StripActiveTD1_0
1	1	/TS_1/TTVol_0/TTDouble_0/StripActiveTD1_0
2	2	/TS_1/TTVol_0/TTDouble_0/StripActiveTD1_0
3	3	/TS_1/TTVol_0/TTDouble_0/StripActiveTD1_0
4	4	/TS_1/TTVol_0/TTDouble_0/StripActiveTD1_0
5	5	/TS_1/TTVol_0/TTDouble_0/StripActiveTD1_0
6	0	/TS_1/TTVol_0/TTSingle_0/StripActiveTS3a_0
7	1	/TS_1/TTVol_0/TTSingle_0/StripActiveTS3a_0
8	2	/TS_1/TTVol_0/TTSingle_0/StripActiveTS3a_0
-1	3	/TS_1/TTVol_0/TTSingle_0/StripActiveTS3a_0
9	0	/TS_1/TTVol_0/TTSingle_0/StripActiveTS3b_0
10	1	/TS_1/TTVol_0/TTSingle_0/StripActiveTS3b_0
11	2	/TS_1/TTVol_0/TTSingle_0/StripActiveTS3b_0
-2	3	/TS_1/TTVol_0/TTSingle_0/StripActiveTS3b_0
12	0	/TS_1/TTVol_0/TTSingle_0/StripActiveTS4a_0
13	1	/TS_1/TTVol_0/TTSingle_0/StripActiveTS4a_0
14	2	/TS_1/TTVol_0/TTSingle_0/StripActiveTS4a_0
-3	3	/TS_1/TTVol_0/TTSingle_0/StripActiveTS4a_0
15	0	/TS_1/TTVol_0/TTSingle_0/StripActiveTS4b_0
16	1	/TS_1/TTVol_0/TTSingle_0/StripActiveTS4b_0
17	2	/TS_1/TTVol_0/TTSingle_0/StripActiveTS4b_0
-4	3	/TS_1/TTVol_0/TTSingle_0/StripActiveTS4b_0
18	0	/TS_1/TTVol_0/TTDouble_0/StripActiveTD2_0
19	1	/TS_1/TTVol_0/TTDouble_0/StripActiveTD2_0
20	2	/TS_1/TTVol_0/TTDouble_0/StripActiveTD2_0
21	3	/TS_1/TTVol_0/TTDouble_0/StripActiveTD2_0
22	4	/TS_1/TTVol_0/TTDouble_0/StripActiveTD2_0
23	5	/TS_1/TTVol_0/TTDouble_0/StripActiveTD2_0

Template of a map

Converter – Single Sided Modules

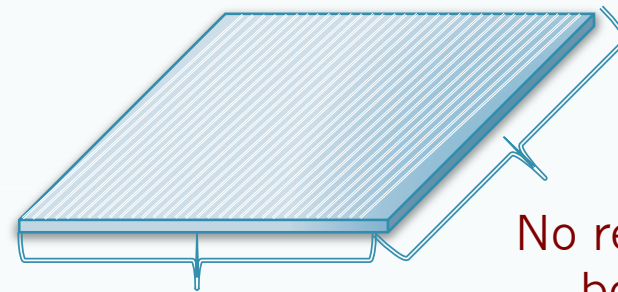


The converter is creating PndMvdStripDigi objects.
The two single sided sensors (components of each of the single sided boxes) are treated independently.

The MVD strip reconstruction tools are designed to work with double sided sensors.

In the definition of the parameters we set one ideal strip on the bottom side, choosing as a pitch the width of the sensor.

When a single sided sensor is hit we fill the TClonesArray with one more digi on the bottom side:

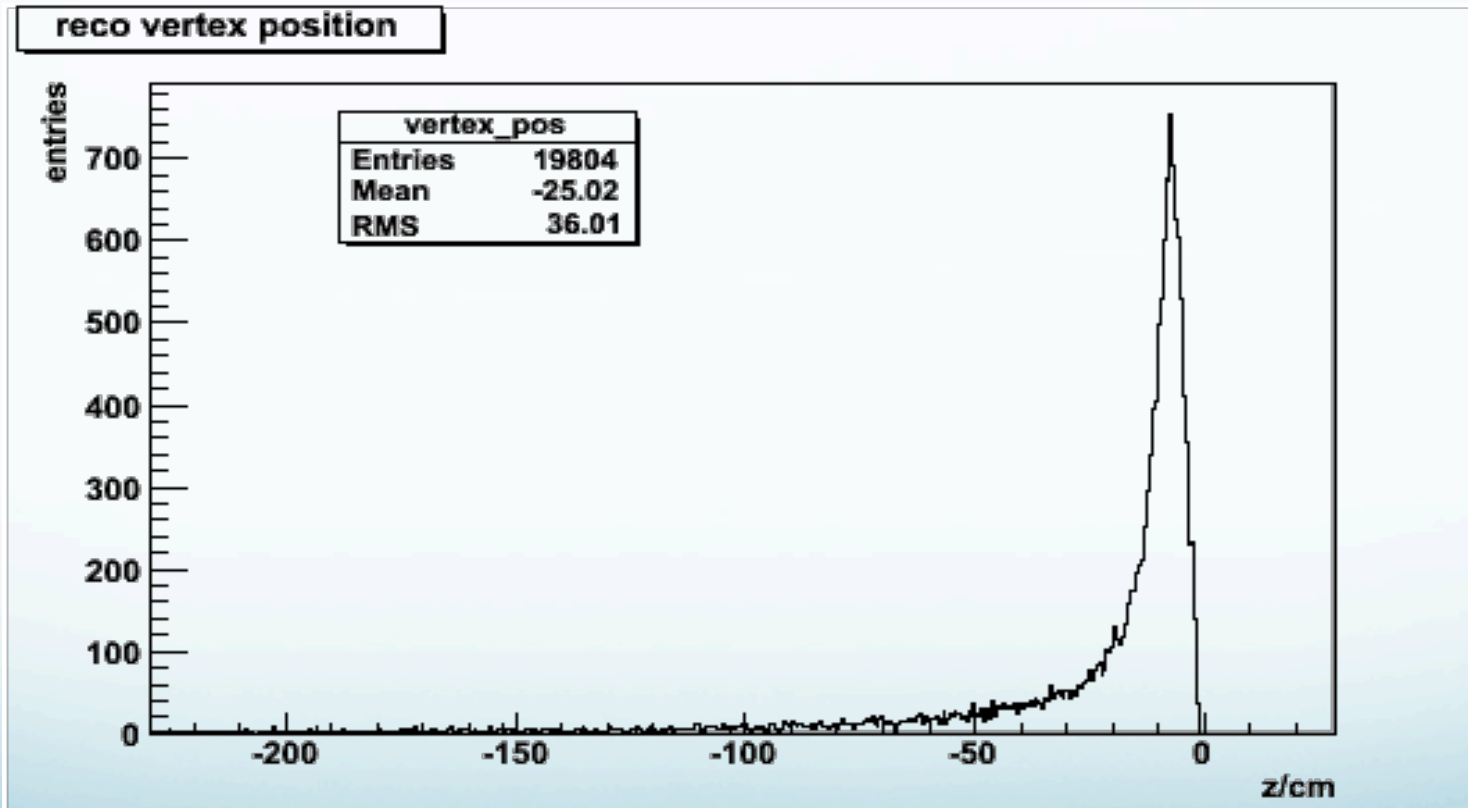


Top side: 384 strips
3 Frontend chips

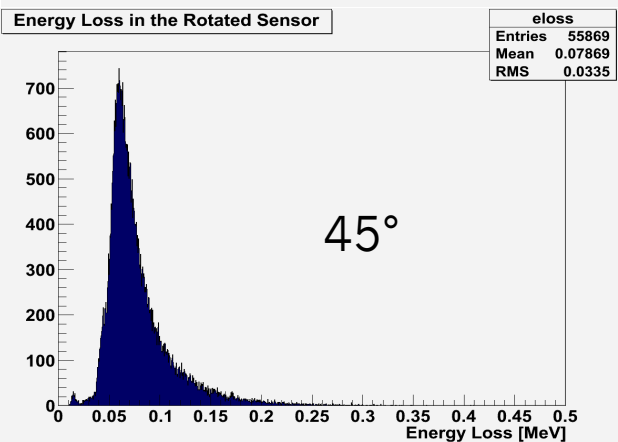
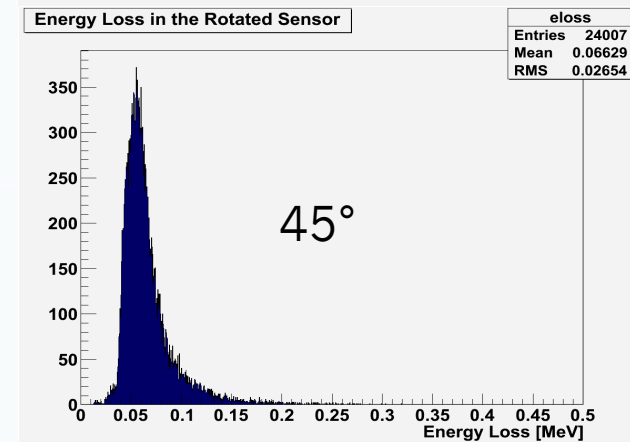
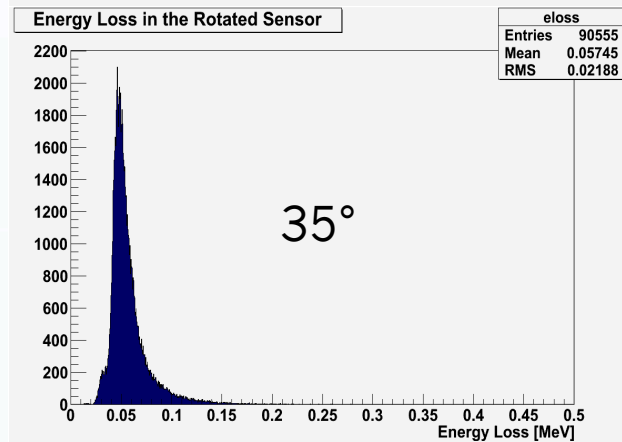
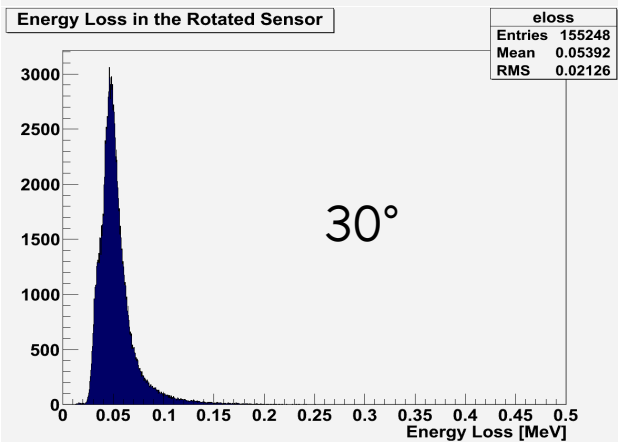
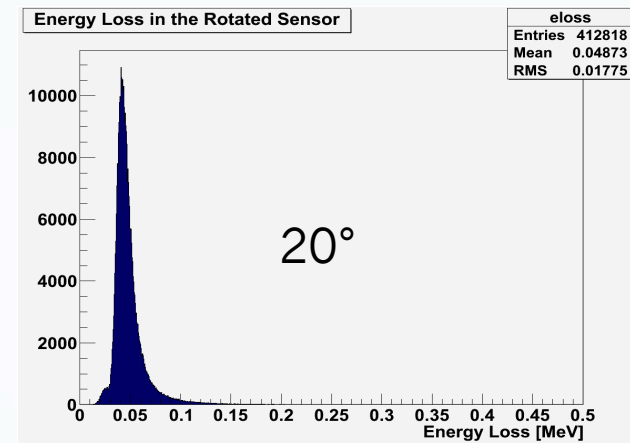
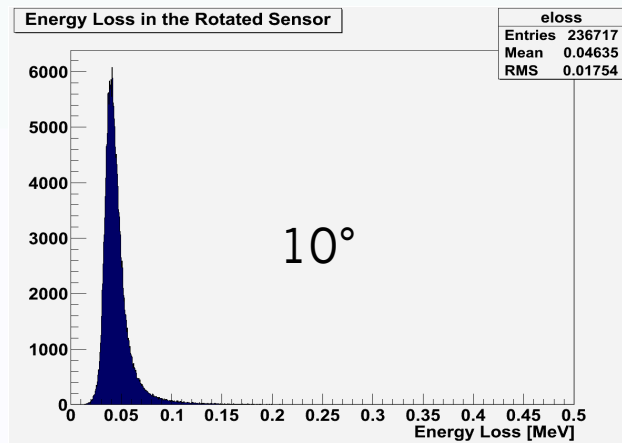
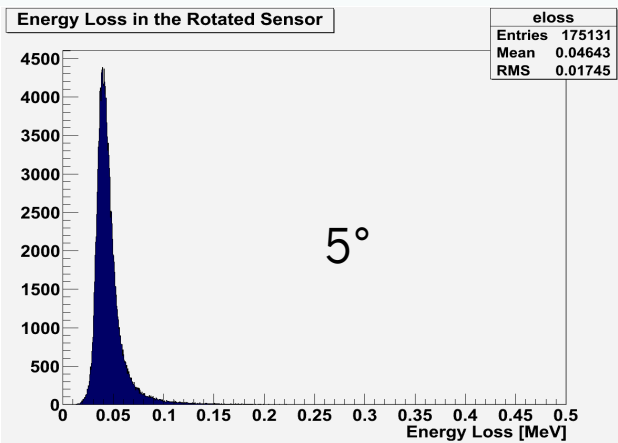
No readout of the bottom side

DetName, Index, ...	Like hits on the top side
Charge	Sum of the values on the top side
Channel	0
Frontend chip	4

Z-reco @ ELSA

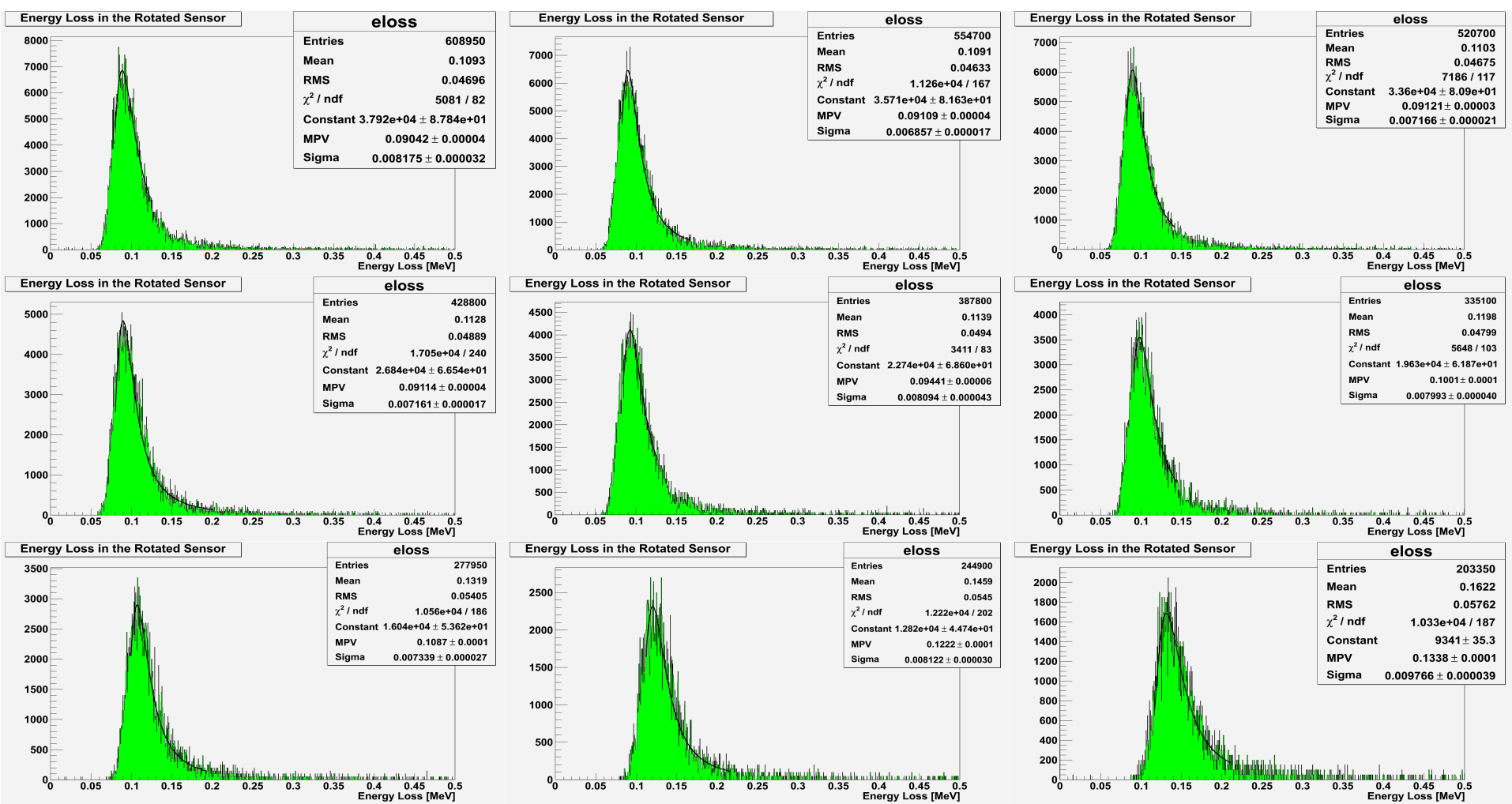


2.95 GeV/c protons @ COSY

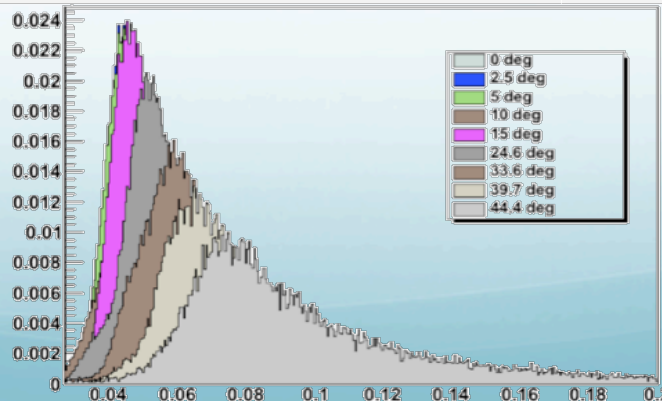


DATA

4 GeV electrons @ DESY



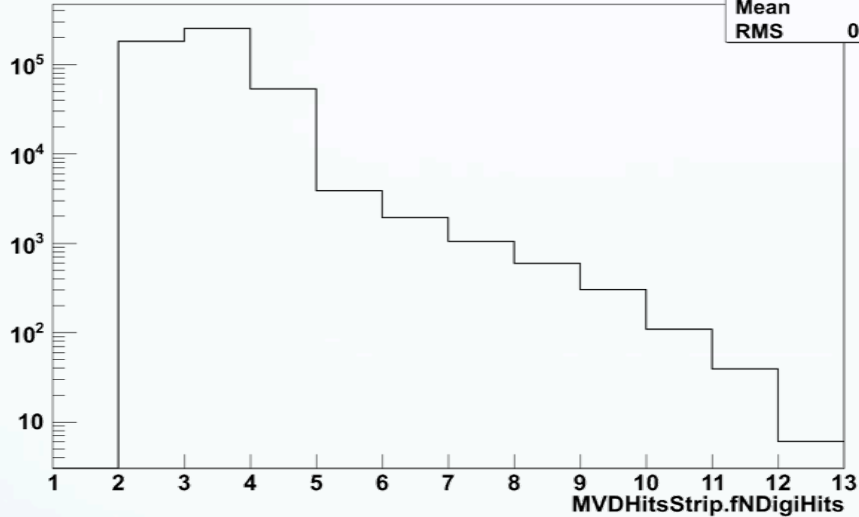
SIMULATIONS



Cluster size

MVDHitsStrip.fNDigiHits {MVDHitsStrip.fZ>110.&&MVDHitsStrip.fZ<120.}

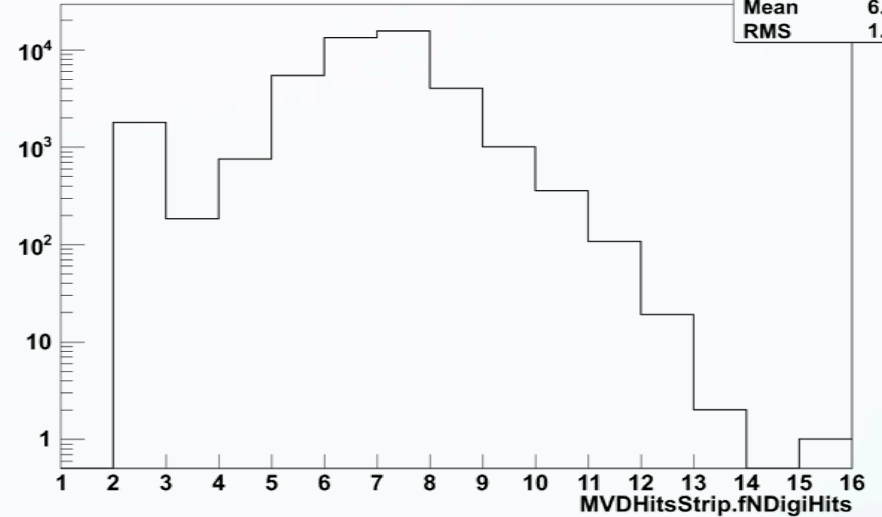
htemp	
Entries	489585
Mean	2.79
RMS	0.7746



0 deg rotation

MVDHitsStrip.fNDigiHits {MVDHitsStrip.fZ>110.&&MVDHitsStrip.fZ<120.}

htemp	
Entries	42375
Mean	6.332
RMS	1.405



45 deg rotation

Simulation Setup

```
G E A N T Version 3.2111    DATE/TIME 110601/1058    R U N    1    *
Data structure Date Time  GVERSN  ZVERSN    *
INIT    110601 1058  3.2111  3.77    *
KINE    110601 1058  3.2111  3.77    *
HITS    110601 1058  3.2111  3.77    *
DIGI    110601 1058  3.2111  3.77    *
```

Standard TPAR for this run are *

```
CUTGAM= 1.00 MeV  CUTELE= 1.00 MeV  CUTNEU= 1.00 MeV
CUTHAD= 1.00 MeV  CUTMUO= 1.00 MeV
BCUTE = 10.00 TeV  BCUTM = 10.00 TeV  DCUTE = 10.00 TeV
DCUTM = 10.00 TeV  PPCUTM= 10.00 TeV
```

```
IPAIR= 0.  ICOMP= 0.  IPHOT= 0.  IPFIS= 0.  IDRAY= 0.  IANNI= 0.  IBREM= 1.  IHADR= 0.
IMUNU= 0.  IDCAY= 0.  ILOSS= 4.  IMULS= 1.  IRAYL= 0.  ILABS= 0.  ISYNC= 0.  ISTR= 0.
```

Energy loss:no delta
rays



Molière model

